TEXAS INSTRUMENTS Data sheet acquired from Harris Semiconductor

间CD4511B供应商

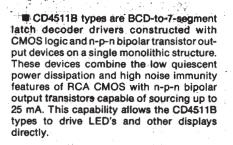
CMOS BCD-to-7-Segment

Latch Decoder Drivers

DISPLAY

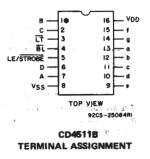
High-Voltage Types (20-Volt Rating)

9



Lamp Test (LT), Blanking (BL), and Latch Enable or Strobe inputs are provided to test the display, shut off or intensity-modulate it, and store or strobe a BCD code, respectively. Several different signals may be multiplexed and displayed when external multiplexing circuitry is used. The CD4511B is supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dualin-line plastic packages (E suffix), and in chip form (H suffix).

These devices are similar to the type MC14511.



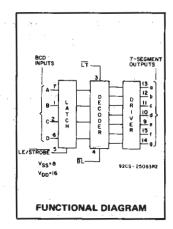
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and a second second

Features:

9205-25087

- High-output-sourcing capability up to 25 mA
- Input latches for BCD Code storage
- Lamp Test and Blanking capability
- 7-segment outputs blanked for BCD input codes > 1001
- 100% tested for quiescent current at 20 V
- Max. input current of 1 μA at 18 V, over full package-temperature range, 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings



Applications:

- Driving common-cathode LED displays
- Multiplexing with common-cathode LED displays
- Driving incandescent displays
- Driving low-voltage fluorescent displays

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to V _{SS} Terminal)
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For T _A = ~55°C to +100°C
For $T_A = \pm 100^{\circ}C$ to $\pm 125^{\circ}C$ Derate Linearity at $12 \text{mW/}^{\circ}C$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (TA)
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 + 1/32 inch (1.59 + 0.79mm) from case for 10s max +265°C

OPERATING CONDITIONS AT TA = 25°C Unless Otherwise Specified

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

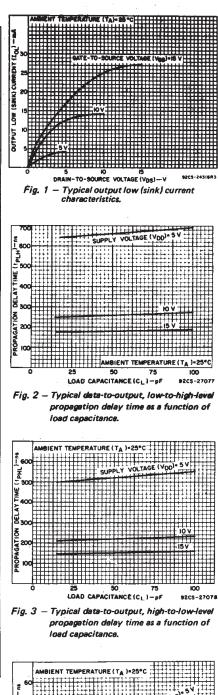
Characteristic	V _{DD}	Min.	Max.	Units
Supply:Voltage Range (T _A): (Full Package Temperature Range)		3	18	v
	5	150	-	ns
Set Up Time (t _S)	10	70	-	ns
-	15	40		ns
	5	0	_	ns
Hold Time (t _H)	10	0	-	ns
	15	0	-	ns
	5	400	_	ns
Strobe Pulse Width (t _W)	10	160	-	ns
	15	100	-	ns

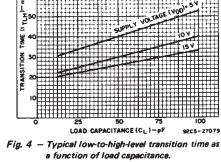
3

CD4511B Types

STATIC ELECTRICAL CHARACTERISTICS

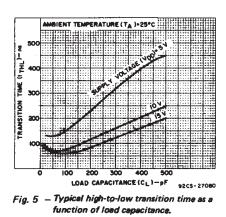
	TEST CONDITIONS													
				LIMITS AT INDICATED TEMPERATURES (°C)										
CHARACTERISTIC	юн	vo	VIN	VDD		[<u> </u>			+25		Unit		
	(mA)	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.			
Quiescent Device	_	-	_	5	5	5	150	150	-	0.04	5			
Current: IDD	-		_	10	10	10	300	300	-	0.04	10	μΑ		
Max.				15	20	20	600	600	-	0.04	20	<u>~</u>		
		-	-	20	100	100	3000	3000	-	0.08	100			
Output Voltage:										1.				
	<u> </u>	-	0,5	5			0.05		· _	0	0.05			
Low-Level VOL			0,10	10			0.05		-	0	0.05	• V -		
Max.	-		0,15	15			0.05		-	0	0.05	•		
			0,5	5	4	4	4.2	4.2	4.1	4.55	-			
High-Level VOH		-	0,10	10	9	9	9.2	9.2	9.1	9,55	- 1	V		
Min.	-		0.15	15	14	14	14.2.	14.2	14.1	14.55				
Input Low	_	0.5,3.8		5	1.5				-	_	1.5			
Voltage, V _{IL}	-	1,8.8	-	10	3				-		3	v		
Max.	· ·	1.5,13.8		15			4		-		4			
Input High	-	0.5,3.8		5	3.5				3.5	-	_			
Voltage, VIH	-	1,8.8		10			7		7	-	_	- v		
Min.		1.5,13.8		15			11		11	_	-			
	0			5	4.0	4.0 4.0 4.20 4.20 4.10 4.55				4.55		[
	5	-						-		4.25		v		
	10				3.80	3.80	3.90	3.90	3.90	4.10				
	15		-	1		-	3.50	3.50	-	3.95	-			
	20	-			3.55	3.55	3.30	-	3.40	3.75	-			
	25			•	3.40	3.40	-		3.10	3.55	~			
	0				9.0	9.0	9.20	9.20	9.10	9.55	-	v		
Output Drive	5					-	-		-	9.25	-			
Voltage:	10	-	-		8.85	8.85	9.00	9.00	9.00	9.15				
High Level VOH	15	-	-	10	-	_	-	- '	-	9.05		ľ		
Min.	20	-	-		8.70	8.70	8.40	8.40	8.60	8.90	-			
	25	-	-		8.60	8.60	-	-	8.30	8.75	· _			
	0	-		•	14.0	14.0	14.20	14.20	14.10	14.55	-			
	5	_	-		-	-	-	-	-	14.30				
	10		_	15	13.90	13.90	14.0	14.0	14.0	14.20	-	v		
	15					-	-	-		14.10	-			
	20				13.75	13.75	13.50	13.50	13.70	13.95	-			
	25		-		13.65	13.65	-	-	13.50	13.80				
A														
Output Low	_	0.4	0.5	5	0.04	0.61	0.42	0.00	0.000			mA		
(Sink) Current,		0.4	0,5 0,10	5 10	0.64	1.5	0.42	0.36	0.51	1 2.6				
^I OL Min,	-	0.5	0,10	10	4.2	4	2.8	2.4	3.4	2.6 6.8	-			
1411(1)		1.5	0,15	13	4.2	4	2.0	2.4	3.4	0.ð				
Input Current, IIN	-	0,18	0,18	18	±0.1	±0.1	±1	±1	-	±10-5	±0.1	μΑ		
Max.								L	L					

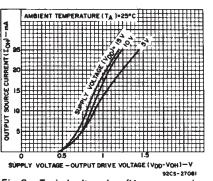


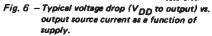


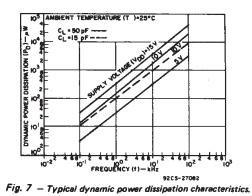
DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω

CHARACTERISTIC	Test Conditions	A	UNITS		
	i V _{DD} Volts	Min.	Тур.	Max.	
Propagation Delay Time:	5		520	1040	
(Data)	10	-	210	420	ns
High-to-Low Level, tPHL	15	-	150	300	
· .	5	_	660	1320	
Low-to-High Level, tPLH	10	-	260	520	ns
	15		180	360	
Propagation Delay Time:	5	_	350	700	
(BL)	10		175	350	ns
High-to-Low Level, tpHL	15	—	125	250	
	5		400	800	
Low-to-High Level, tpLH	10	-	175	350	ns
	15		150	300	
Propagation Delay Time:	5	-	250	500	
(LT)	10	-	125	250	ns
High-to-Low Level, tPHL	15	_	85	170	
	5		150	300	
Low-to-High Level, tpLH	10	-	75	150	ns
	15	-	50	100	
Transition Time:	5	_	40	80	
	10	_	30	60	ns
Low-to-High Level, tTLH	15	-	25	50	· . ,
	5		125	310	
	10	-	75	185	ns
High-to-Low Level, THL	15	-	65	160	
	5	150	75	-	
Minimum Set-Up Time, t _S	10	70	35	-	ns
	15	40	20	-	
••• · · · · · · ·	5	0	-75	-	
Minimum Hold Time, t _H	10	0	35	-	ns
	15	0	-20		
Construction De la Marca	5	400	200	- 1	
Strobe Pulse Width, tw	10 15	160 100	80 50		ns
	15	100			
Input Capacitance, CIN		_	5	7.5	pF





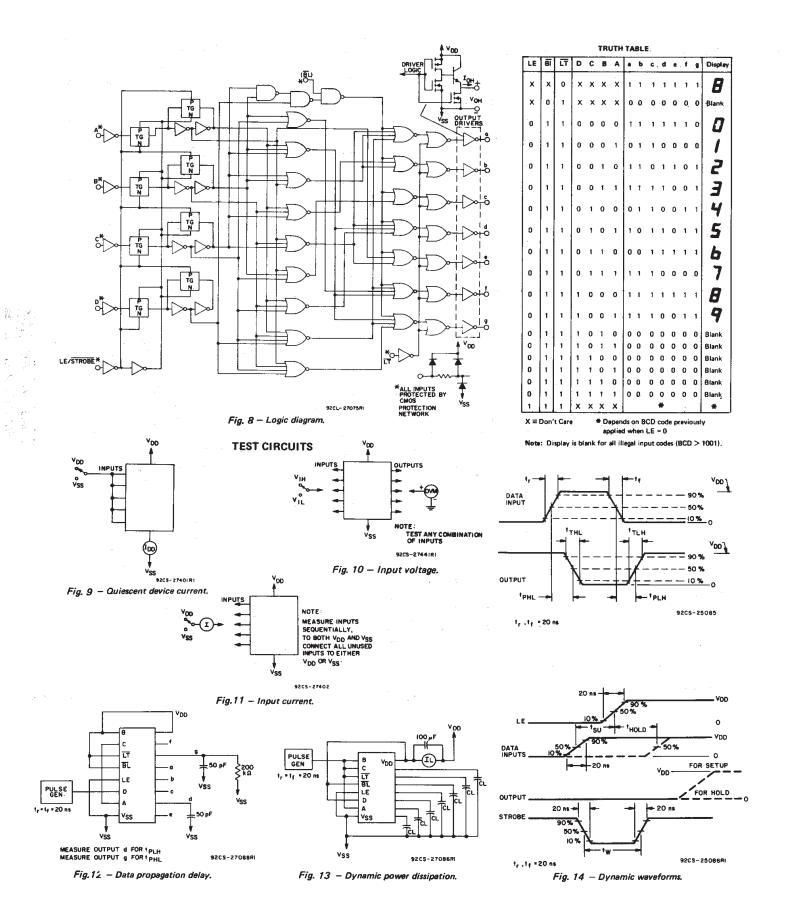




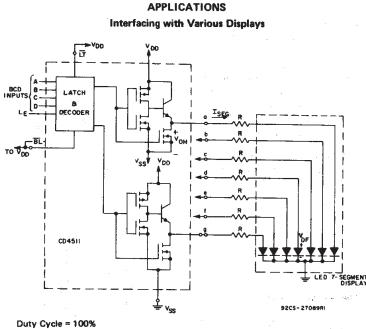


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CD4511B Types



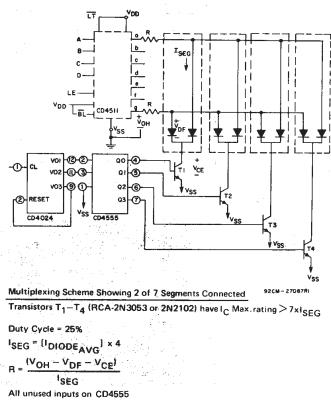
CD4511B Types



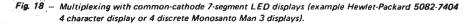
ISEG = IDIODEAVG. = 20 mA at Luminous Intensity/Segment = 250 microcandles

$$R = \frac{V_{OH} - V_{DF}}{I_{SEG}}$$

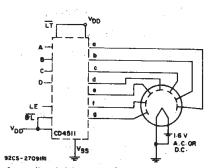
Fig. 15 - Driving common-cathode 7-segment LED displays (example Hewlet-Packard 5082-7740).



are connected to VDD or VSS.

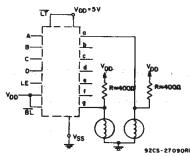


Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .



A medium-brightness intensity display can be obtained with low-voltage fluorescent displays such as the Tung-Sol Digivac S/G** Series. ** Trademark Tung-Sol Division Wagner Electric Co.

Fig. 16 - Driving low-voltage fluorescent displays.

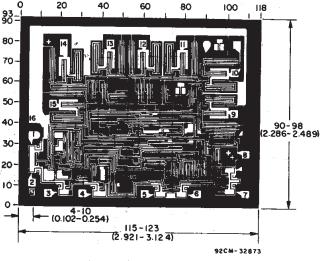


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COMMERCIAL CMOS HIGH VOLTAGE ICs

2 of 7 Segments Shown Connected Besistors R from VDD to each 7-segment driver output are chosen to keep all Numitron segments slightly on and warm.

Fig. 17 – Driving incandescent displays (RCA Numitron DR2000 series displays).



Dimensions and pad layout for CD4511B chip.

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